KID65001APV/AFV ~ KID65004APV/AFV

BIPOLAR DIGITAL INTEGRATED CIRCUIT

7 CIRCUIT DARLINGTON TRANSISTOR ARRAY

FEATURES

- Output Current : 500mA Max.
- High Sustaining Voltage Outputs : 50V Min.
- Output Clamp Diodes
- Inputs Compatible With Various Types of Logic.
- PKG Type APV : DIP-16Pin, AFV : FLP-16Pin

TYPE	INPUT RESISTOR	DESIGNATION
KID65001APV/AFV	No (External)	General Purpose
KID65002APV/AFV	Zener Diode 7V+10.5kΩ	14~25V P-MOS
KID65003APV/AFV	2.7kΩ	TTL, 5V C-MOS
KID65004APV/AFV	10.5kΩ	6~15V P-MOS, C-MOS

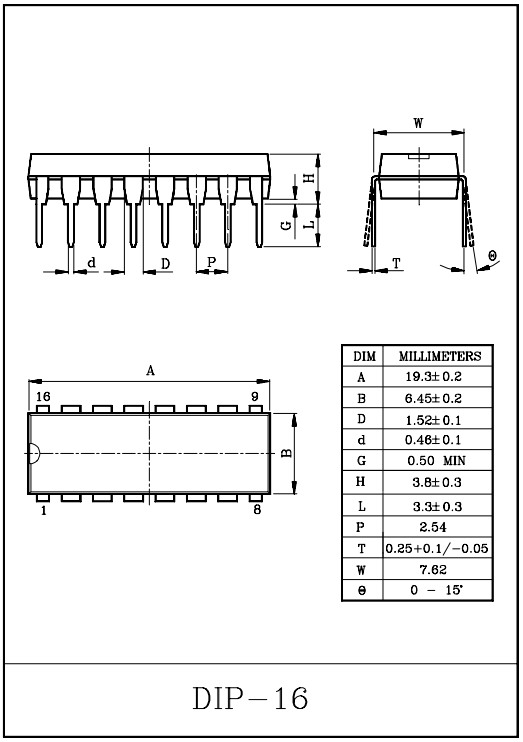
DESCRIPTION:

The KID65001APV/AFV Series are high-voltage, high-current darlington transistor array comprised of seven NPN darlington pairs. All units feature internal clamp diodes for switching inductive loads.

MAXIMUM RATINGS (Ta=25℃, unless otherwise noted)

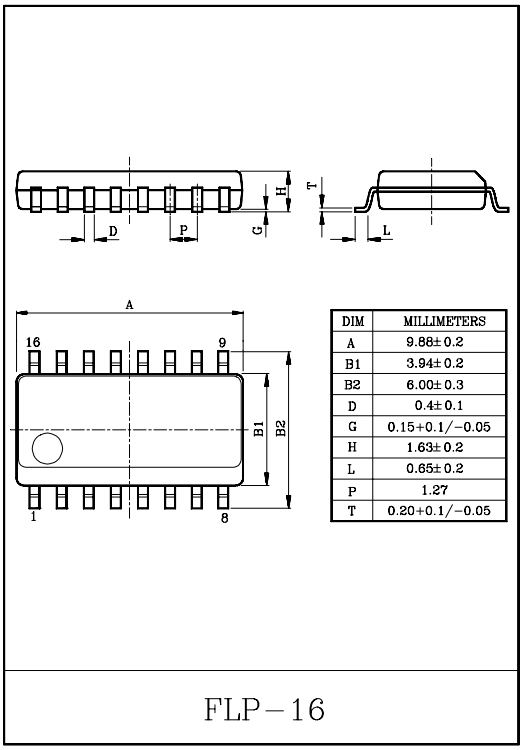
CHARACTERISTIC		SYMBOL	RATING	UNIT
Output Sustaining Voltage		$V_{CE(SUS)}$	50	V
Output Current		I_{OUT}	500	mA
Input Voltage		V_{IN}*	-0.5~+30	V
Input Current		I_{IN}**	25	mA
Clamp Diode	Reverse Voltage	V_R	50	V
	Forward Current	I_F	500	mA
GND Terminal Current		I_{GND}	2.8	A
Power Dissipation	APV	P_D	1.47	W
	AFV		0.54	W
Operating Temperature		T_{opr}	-40~85	℃
Storage Temperature		T_{stg}	-55~150	℃

*Except KID65001APV/AFV, **Only KID65001APV/AFV



DIM	MILLIMETERS
A	19.3± 0.2
B	6.45± 0.2
D	1.52± 0.1
d	0.46± 0.1
G	0.50 MIN
H	3.8± 0.3
L	3.3± 0.3
P	2.54
T	0.25+0.1/−0.05
W	7.62
θ	0 ~ 15°

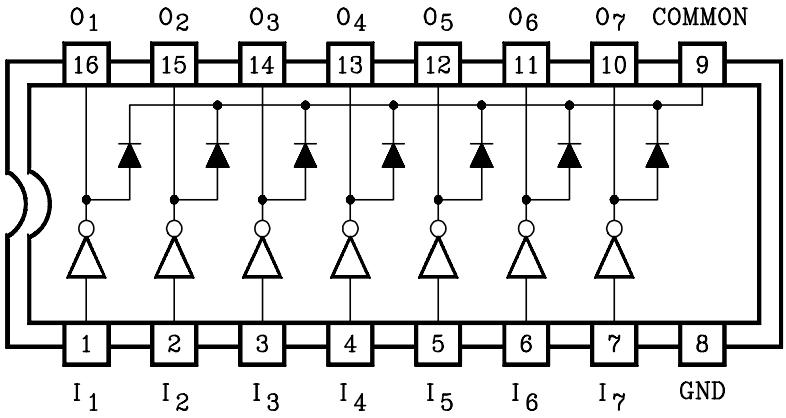
DIP-16



DIM	MILLIMETERS
A	9.86± 0.2
B1	3.94± 0.2
B2	6.00± 0.3
D	0.4± 0.1
G	0.15+0.1/−0.05
H	1.63± 0.2
L	0.65± 0.2
P	1.27
T	0.20+0.1/−0.05

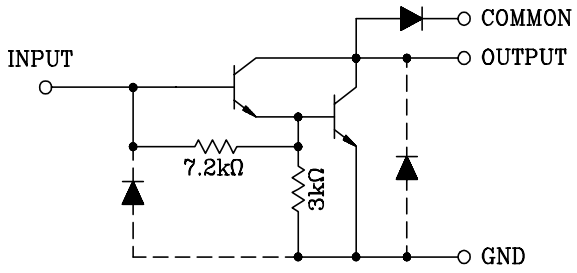
FLP-16

PIN CONNECTION (TOP VIEW)

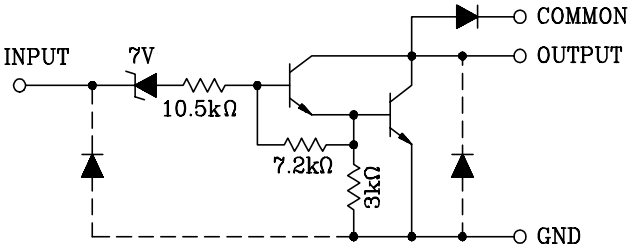


SCHEMATICS (EACH DRIVER)

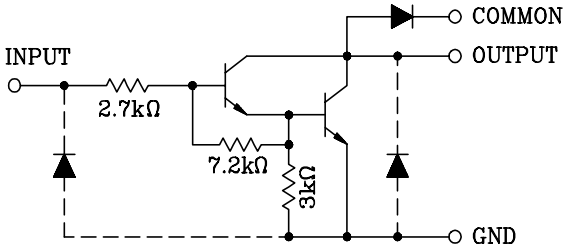
KID65001APV/AFV



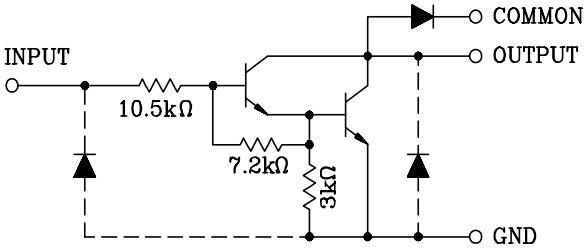
KID65002APV/AFV



KID65003APV/AFV



KID65004APV/AFV



RECOMMENDED OPERATING CONDITIONS (Ta=-40~85℃)

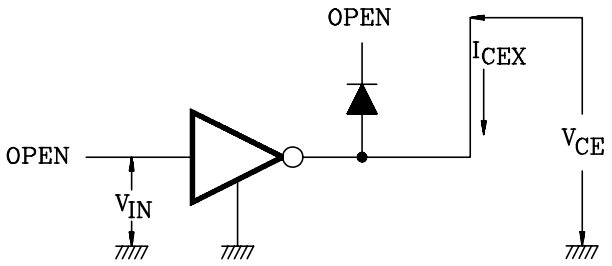
CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Output Sustaining Voltage		$V_{CE(SUS)}$		0	-	50	V
Output Current		I_{OUT}	T_{PW}=25ms, DF=10%, 7 Circuits	0	-	400	mA
			T_{PW}=25ms, DF=30%, 7 Circuits	0	-	200	
Input Voltage		V_{IN}	Except KID65001APV/AFV	0	-	30	V
Input Current		I_{IN}	Only KID65001APV/AFV	0	-	5	mA
Clamp Diode Reverse Voltage		V_R		-	-	50	V
Clamp Diode Forward Current		I_F		-	-	400	mA
Power Dissipation	APV	P_D	Ta=Topr(max)	-	-	0.52	W
	AFV			-	-	0.32	

ELECTRICAL CHARACTERISTICS (Ta=25℃, unless otherwise noted)

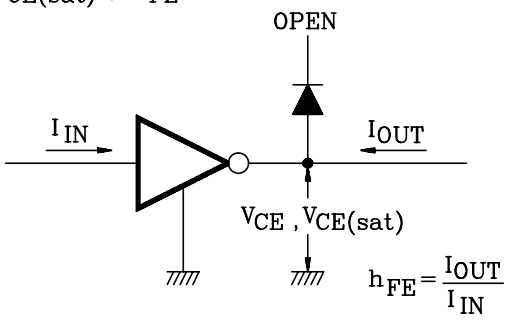
CHARACTERISTICS		SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Output Leak Current		I_{CEX}	1	V_{CE}=50V, Ta=25℃	-	-	50	μA
				V_{CE}=50V, Ta=85℃	-	-	100	
	KID65002APV/AFV			V_{CE}=50V, V_{IN}=6V	-	-	500	
	KID65004APV/AFV			V_{CE}=50V, V_{IN}=1V	-	-	500	
Collector-Emitter Saturation Voltage		$V_{CE(sat)}$	2	I_{OUT}=350mA, I_{IN}=500μA	-	1.3	1.6	V
				I_{OUT}=200mA, I_{IN}=350μA	-	1.1	1.3	
				I_{OUT}=100mA, I_{IN}=250μA	-	0.9	1.1	
Input Current	KID65002APV/AFV	$I_{IN(ON)}$	3	V_{IN}=17V	-	0.82	1.25	mA
	KID65003APV/AFV			V_{IN}=3.85V	-	0.93	1.35	
	KID65004APV/AFV			V_{IN}=5V	-	0.35	0.5	
				V_{IN}=12V	-	1.0	1.45	
		$I_{IN(OFF)}$	4	I_{OUT}=500μA, Ta=85℃	50	65	-	μA
Input Voltage	KID65002APV/AFV	$V_{IN(ON)}$	5	V_{CE}=2V, I_{OUT}=300mA	-	-	13	V
	KID65003APV/AFV			V_{CE}=2V, I_{OUT}=200mA	-	-	2.4	
				V_{CE}=2V, I_{OUT}=250mA	-	-	2.7	
				V_{CE}=2V, I_{OUT}=300mA	-	-	3.0	
	KID65004APV/AFV			V_{CE}=2V, I_{OUT}=125mA	-	-	5.0	
				V_{CE}=2V, I_{OUT}=200mA	-	-	6.0	
				V_{CE}=2V, I_{OUT}=275mA	-	-	7.0	
				V_{CE}=2V, I_{OUT}=350mA	-	-	8.0	
DC Current Transfer Ratio		h_{FE}	2	V_{CE}=2V, I_{OUT}=350mA	1000	-	-	
Clamp Diode Reverse Current		I_R	6	V_R=50V, Ta=25℃	-	-	50	μA
				V_R=50V, Ta=85℃	-	-	100	
Clamp Diode Forward Voltage		V_F	7	I_F=350mA	-	-	2.0	V
Input Capacitance		C_{IN}			-	15	-	pF
Turn-ON Delay		t_{ON}	8	V_{OUT}=50V, R_L=163Ω C_L=15pF	-	0.1	-	μS
Turn-OFF Delay		t_{OFF}			-	0.2	-	

TEST CIRCUIT

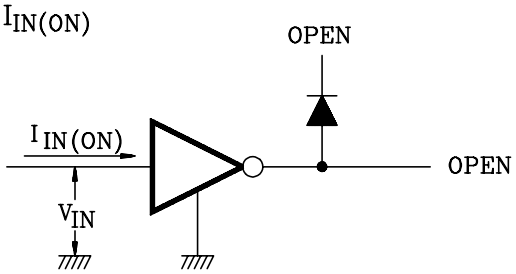
1. I_{CEX}



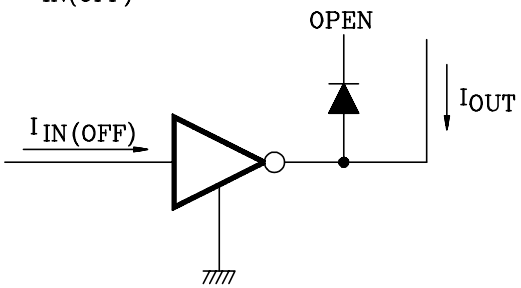
2. $V_{CE(sat)}$, h_{FE}



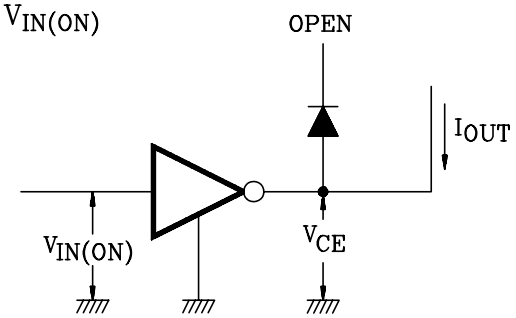
3. $I_{IN(ON)}$



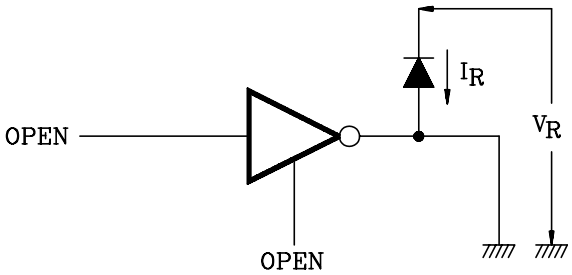
4. $I_{IN(OFF)}$



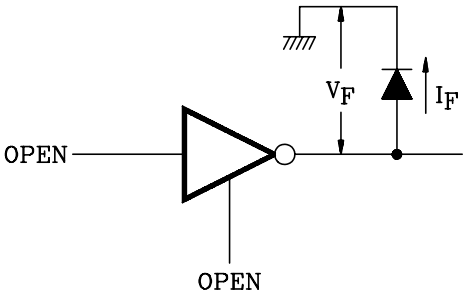
5. $V_{IN(ON)}$



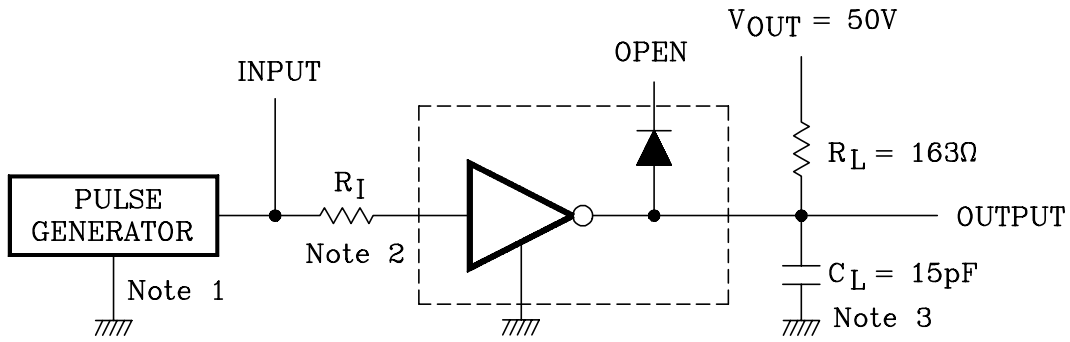
6. I_R

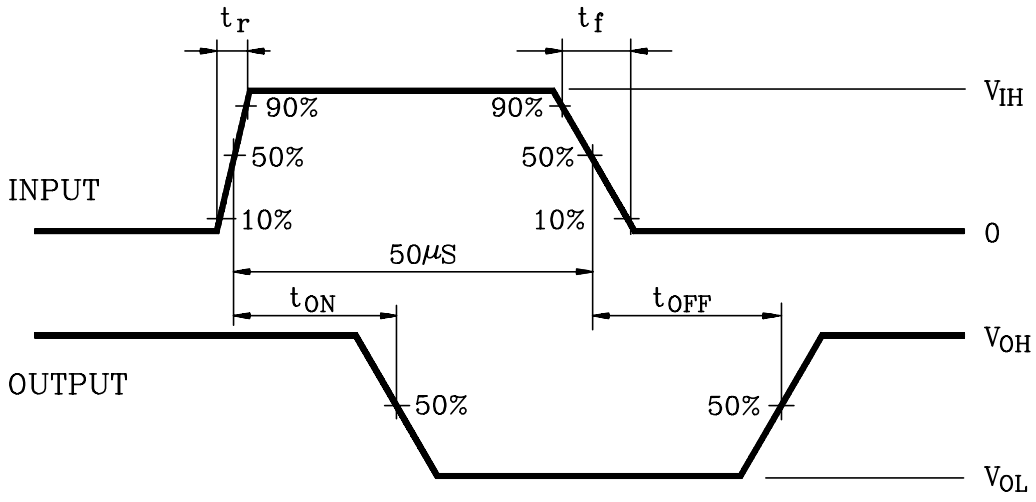


7. V_F



8. t_{ON} , t_{OFF}





Notes : 1. Pulse Width 50μS, Duty Cycle 10%
Output Impedance 50Ω, $t_r \leqq 5$ns, $t_f \leqq 10$ns

2. See below

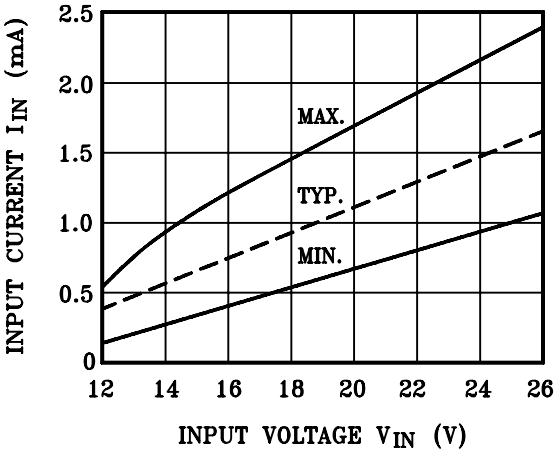
Input Conditions

Type Number	R_I	V_{IH}
KID65001APV/AFV	2.7kΩ	3V
KID65002APV/AFV	0	13V
KID65003APV/AFV	0	3V
KID65004APV/AFV	0	8V

3. C_L includes probe and jig capacitance.

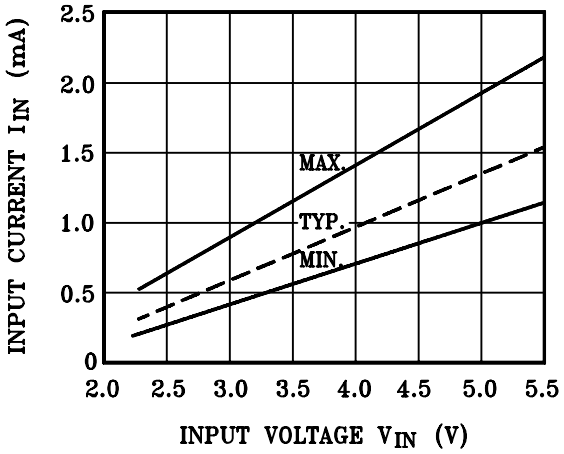
KID65002APV/AFV

I_{IN} – V_{IN}



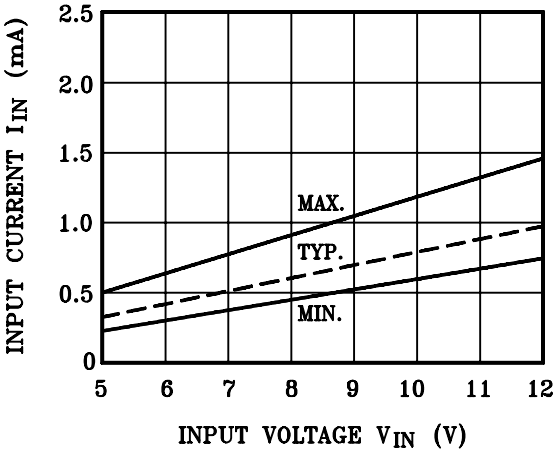
KID65003APV/AFV

I_{IN} – V_{IN}

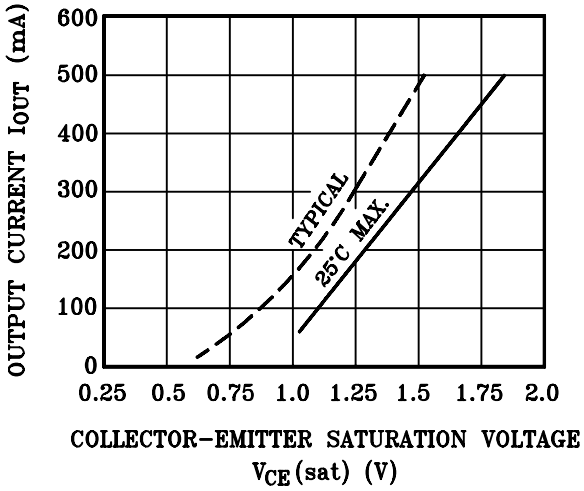


KID65004AVP/AFV

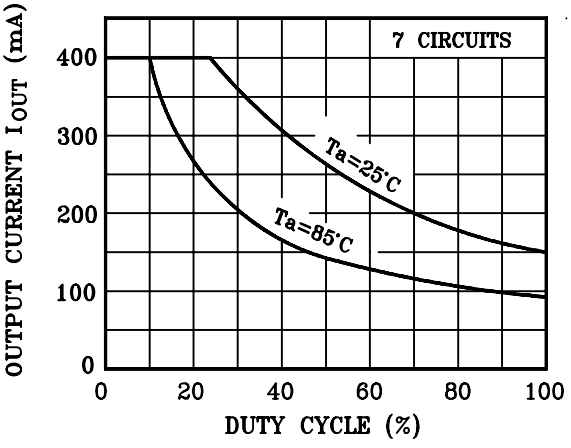
I_{IN} – V_{IN}



I_{OUT} – $V_{CE(sat)}$



I_{OUT} – DUTY CYCLE



P_D – Ta

